### **General Description**

The MAX4762-MAX4764/MAX4764A/MAX4765 dual SPDT (single-pole/double-throw) switches feature negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single +1.8V to +5.5V supply and have low  $0.6\Omega$  on-resistance, making them ideal for switching audio signals.

The MAX4763/MAX4765 include a comparator that can be used for headphone detection or a mute/send key function. The MAX4764/MAX4764A/MAX4765 have an internal shunt switch to automatically discharge any capacitance at the NO and NC connection points. This reduces click-and-pop sounds that occur when switching audio signals between precharged points.

These SPDT switches are available in space-saving µMAX<sup>®</sup>, TDFN, thin QFN, and UCSP<sup>™</sup> packages and operate over the -40°C to +85°C extended temperature range.

### **Applications**

**Cell Phones** 

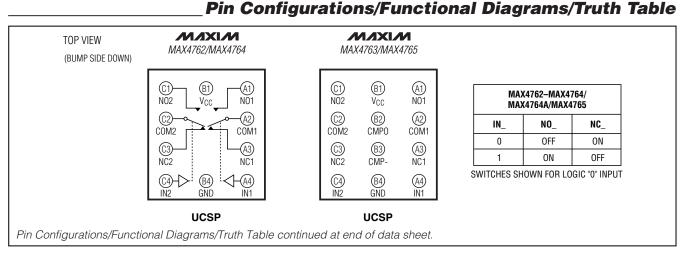
PDAs and Handheld Devices

Notebook Computers

MP3 Players

µMAX is a registered trademark and UCSP is a trademark of Maxim Integrated Products, Inc.

Ordering Information continued at end of data sheet. Selector Guide appears at end of data sheet.



## 

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

### Features

- Distortion-Free Negative Signal Throughput Down to V<sub>CC</sub> - 5.5V
- Comparator for Headphone or Mute Detection (MAX4763/MAX4765)
- Internal Shunt Resistor Reduces Click/Pop (MAX4764/MAX4764A/MAX4765)
- Low On-Resistance (RON) 0.6Ω at +2.7V Supply
- 0.25Ω On-Resistance Flatness
- 0.05Ω On-Resistance Matching
- +1.8V to +5.5V Supply Voltage
- -70dB Crosstalk (100kHz)
- -65dB Off-Isolation (100kHz)
- 0.01% Total Harmonic Distortion
- Available in µMAX, TDFN, Thin QFN, and UCSP Packages

### **Ordering Information**

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4762ETB	-40°C to +85°C	10 TDFN	ACG
MAX4762EUB	-40°C to +85°C	10 µMAX	—
MAX4762EBC-T	-40°C to +85°C	12 UCSP-12	ABU

### **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to GND.)

V <sub>CC</sub> , IN_, CMP0.3V to +6.0V
$COM_{, NO_{, NC_{, MC_{, MC}$
CMPO0.3V to (V <sub>CC</sub> + 0.3V)
Closed-Switch Continuous Current COM_, NO_, NC±150mA
Open-Switch Continuous Current NO_, NC_
(MAX4764/MAX4764A/MAX4765)±30mA
Peak Current COM_, NO_, NC_
(pulsed at 1ms, 50% duty cycle)±300mA
Peak Current COM_, NO_, NC_
(pulsed at 1ms, 10% duty cycle)±400mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
10-Pin TDFN (derate 24.4mW/°C above +70°C)1951mW
10-Pin µMAX (derate 5.6mW/°C above +70°C)444mW

12-Bump UCSP (MAX4762/MAX4764)	
(derate 5.6mW/°C above +70°C)	449mW
12-Bump UCSP (MAX4763/MAX4765)	
(derate 6.5mW/°C above +70°C)	519mW
12-Pin Thin QFN (derate 16.9mW/°C above +70°C	C)1349mW
ESD Method 3015.7	±2kV
Operating Temperature Range4	0°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range65	°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Bump Temperature (soldering)	
Infrared (15s)	+220°C
Vapor Phase (60s)	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

( $V_{CC}$  = +2.7V to +5.5V,  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are at  $V_{CC}$  = +3.0V,  $T_A$  = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
ANALOG SWITCH		•						
Analog Signal Range (Note 2)	V <sub>NO_</sub> , V <sub>NC_</sub> , V <sub>COM_</sub>			V <sub>CC</sub> - 5.5		V <sub>CC</sub>	V	
On-Resistance	Denvines	$V_{CC} = 2.7V$ ; $V_{NC}$ or $V_{NO} =$	$T_A = +25^{\circ}C$		0.6	0.85	Ω	
(Notes 3 and 4)	Ron(nc), Ron(no)	V <sub>CC</sub> - 5.5V, -1V, 0V, 1V, 2V, V <sub>CC</sub> ; I <sub>COM</sub> _ = 100mA	T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>			0.95		
On-Resistance Match			$T_A = +25^{\circ}C$		0.05	0.1		
Between Channels (Notes 3, 4, and 5)	ΔR <sub>ON</sub>	$V_{CC} = 2.7V, V_{NC}$ or $V_{NO} = 0V,$ $I_{COM} = 100mA$	$T_A = T_{MIN}$ to $T_{MAX}$			0.15	Ω	
On-Resistance Flatness (Notes 4 and 6)	R <sub>FLAT(NC)</sub>	V <sub>CC</sub> = 2.7V; V <sub>NC</sub> _or V <sub>NC</sub> = -1V, 0V, 1V, 2V, V <sub>CC</sub> ; I <sub>COM</sub> = 100mA	$T_A = +25^{\circ}C$		0.25	0.4		
			$T_A = T_{MIN}$ to $T_{MAX}$			0.45	Ω	
Shunt Switch Resistance	R <sub>SH</sub>	$\label{eq:MAX4764} \begin{array}{l} \mbox{MAX4764}\mbox{MAX4765} \mbox{ only,} \\ \mbox{I}_{NO\_} \mbox{ or } \mbox{I}_{NC\_} = 10\mbox{mA}, \mbox{V}_{CC} = 2.7\mbox{V} \end{array}$	$T_A = T_{MIN}$ to $T_{MAX}$		25	50	Ω	
NO_, NC_ Off-Leakage Current		MAX4762/MAX4763 only (Note 7), $V_{CC} = 2.7V$ , switch open;	$T_A = +25^{\circ}C$	-2		+2	۳Å	
(Notes 8 and 9)	I <sub>NC_(OFF)</sub>	$V_{NC_}$ or $V_{NO_}$ = -2.5V, +2.5V; $V_{COM_}$ = +2.5V, -2.5V	T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>	-10		+10	— nA	
COM_ On-Leakage Current (Notes 8 and 9)	ICOM_(ON)	$V_{CC} = 2.7V$ , switch closed; $V_{NC}$ or $V_{NO} = -2.5V$ , +2.5V, or floating; $V_{COM} = -2.5V$ , +2.5V, or floating	$T_A = +25^{\circ}C$	-6		+6	nA	
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>	-50		+50	ПА	

## **ELECTRICAL CHARACTERISTICS (continued)**

(V<sub>CC</sub> = +2.7V to +5.5V,  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are at V<sub>CC</sub> = +3.0V,  $T_A$  = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIO	NS	MIN	ТҮР	MAX	UNITS
DYNAMIC CHARACTERIST	ICS						
		$V_{CC} = 2.7V, V_{NO} = 1.5V;$ for	$T_A = +25^{\circ}C$		25	80	
Turn On Time		$NO_{,}VIN_{} = 0V \text{ to } V_{CC}; \text{ for}$	$T_A = T_{MIN}$ to $T_{MAX}$			80	
Turn-On Time	ton	NC_, $V_{IN}$ = $V_{CC}$ to 0V; R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35pF, Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$ (MAX4764A)		225	500	ns
		V <sub>CC</sub> = 2.7V, V <sub>NC</sub> = 1.5V; for	$T_A = +25^{\circ}C$		20	70	
Turn-Off Time	toff	NO_, $V_{IN}$ = V <sub>CC</sub> to 0V; for	$T_A = T_{MIN}$ to $T_{MAX}$			70	1
	UFF	NC_, $V_{IN}$ = 0V to $V_{CC}$ ; $R_L$ = 300 $\Omega$ , $C_L$ = 35pF, Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$ (MAX4764A)		225	500	ns
Break-Before-Make Time Delay	tD	$V_{CC} = 2.7V, V_{N_{-}} = 1.5V, \text{ for}$ NO_, V <sub>IN_</sub> = V <sub>CC</sub> to 0V; for NC_, V <sub>IN_</sub> = 0V to V <sub>CC</sub> ; R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35pF, Figure 3	T <sub>A</sub> = +25°C	1	7		ns
Charge Injection	Q	$V_{COM}$ = 0V, $C_{L}$ = 1.0nF, Figu	re 4		150		рС
Off-Isolation (Note 10)	VISO	f = 100kHz, V <sub>COM</sub> = 1V <sub>RMS</sub> , R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, Figure 5			-65		dB
Crosstalk	VCT	f = 100kHz, V <sub>COM</sub> = 1V <sub>RMS</sub> , R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 5pF, Figure 5			-70		dB
Power-Supply Rejection Ratio	PSRR	f = 10kHz, $V_{COM}$ = 1 $V_{RMS}$ , $R_L$ = 50 $\Omega$ , $C_L$ = 5pF			60		dB
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 5pF, Figure 5			27		MHz
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V <sub>COM</sub> = 0.5V <sub>P-P</sub> , DC Bias = 0, R <sub>L</sub> = 32 $\Omega$			0.01		%
NO_, NC_ Off-Capacitance	C <sub>NO_(OFF)</sub> C <sub>NC_(OFF)</sub>	f = 1MHz, V <sub>COM</sub> = 0.5V <sub>P-P</sub> , E	DC Bias = 0, Figure 6		50		pF
COM On-Capacitance	CCOM_(ON)	f = 1MHz, V <sub>COM</sub> = 0.5V <sub>P-P</sub> , [	DC Bias = 0, Figure 6		200		pF
DIGITAL I/O (IN_)							
		V <sub>CC</sub> = 2.7V to 3.6V		1.4			
Input-Logic High Voltage	VIH	$V_{CC} = 4.2V$ to 5.5V		2.0			V
		V <sub>CC</sub> = 2.7V to 5.5V (MAX4764A only)		1.6			
Input-Logic Low Voltage		V <sub>CC</sub> = 2.7V to 3.6V				0.5	V
	VIL	V <sub>CC</sub> = 4.2V to 5.5V				0.8	
		V <sub>CC</sub> = 2.7V to 5.5V (MAX4764A only)				0.5	
Input Leakage Current	I <sub>IN</sub>	$V_{IN}$ = 0V or $V_{CC}$		-1		+1	μΑ
COMPARATOR (MAX4763/	MAX4765)		Г				1
Comparator Threshold					V <sub>CC</sub> / 3		V

### **ELECTRICAL CHARACTERISTICS (continued)**

(V<sub>CC</sub> = +2.7V to +5.5V,  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are at V<sub>CC</sub> = +3.0V,  $T_A$  = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITI	ONS	MIN	ТҮР	MAX	UNITS
Comparator Output High Voltage		ISOURCE = 1mA		V <sub>CC</sub> - 0.4V			V
Comparator Output Low Voltage		I <sub>SINK</sub> = 1mA				0.4V	V
Comparator Input Leakage Current		V <sub>CMP-</sub> = 0 to 2.7V		-100		+100	nA
Comparator Switching Time		$V_{CC}$ = 2.7V, $V_{CMP-}$ = 0V to $V_{CC}$ , from 50% of $V_{CMP-}$ to 50% of $V_{CMPO}$			1	2	μs
POWER SUPPLY		·					
Power-Supply Range	V <sub>CC</sub>			1.8		5.5	V
	1+	$V_{CC} = 5.5V, V_{IN} = 0V \text{ or}$ $V_{CC}$	MAX4763/MAX4765		5	10	
Supply Current			MAX4762/MAX4764/ MAX4764A		0.01	1	
		V <sub>CC</sub> = 5.5V, V <sub>IN</sub> = 1.8V	MAX4764A		5	10	μΑ
		V <sub>CC</sub> = 4.2V, V <sub>IN</sub> = 1.8V (Note 11)	MAX4764A		2	5	

**Note 1:** UCSP and TDFN parts are 100% tested at  $T_A = +25^{\circ}$ C only, and guaranteed by design over the specified temperature range. Thin QFN parts are 100% tested at  $T_A = +85^{\circ}$ C only, and guaranteed by design over the specified temperature range.

Note 2: Signals on COM\_, NO\_, or NC\_ exceeding V<sub>CC</sub> are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Note 3: Thin QFN and UCSP are guaranteed by design; not production tested.

Note 4: I<sub>COM</sub> for UCSP is 10mA.

**Note 5:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: MAX4764/MAX4764A/MAX4765 have an internal shunt switch when in off-state, which determines OFF current.

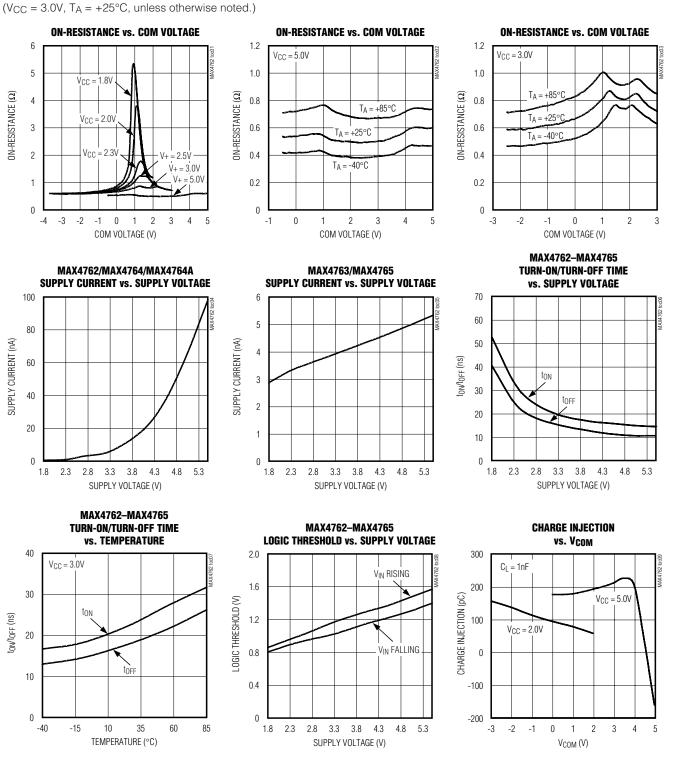
Note 8: Leakage parameters are 100% tested at maximum-rated hot operating temperature and guaranteed by design at T<sub>A</sub> = +25°C.

**Note 9:** UCSP parts are guaranteed by design.

Note 10: Off-isolation = 20log<sub>10</sub> (V<sub>COM</sub> / V<sub>NO</sub>), V<sub>COM</sub> = output, V<sub>NO</sub> = input to off switch.

Note 11: Guaranteed by design, not production tested.

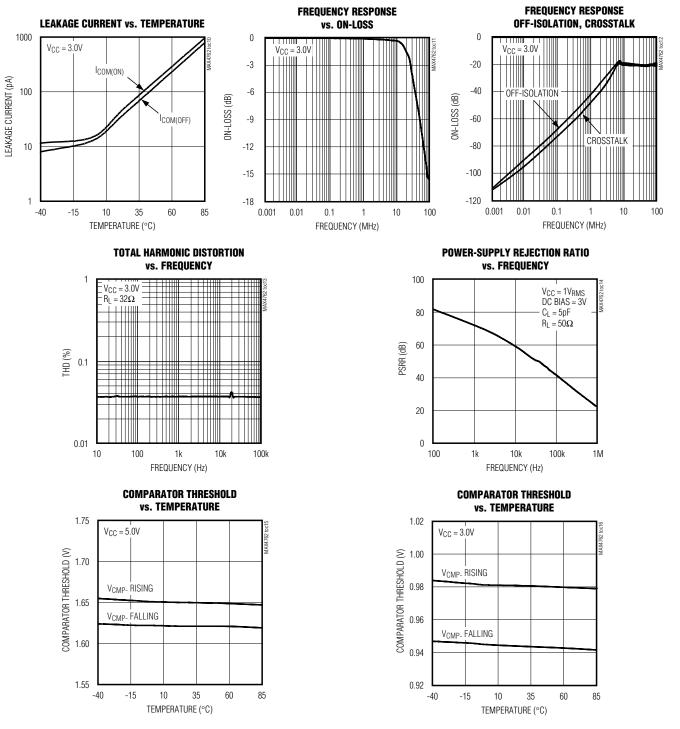
**Typical Operating Characteristics** 



MAX4762-MAX4764/MAX4764A/MAX4765

(V<sub>CC</sub> = 3.0V, T<sub>A</sub> =  $+25^{\circ}C$ , unless otherwise noted.)

### Typical Operating Characteristics (continued)



/M/IXI/M

## \_Pin Description (MAX4762/MAX4764/MAX4764A)

P	IN			
10-µMAX 10-TDFN	12-UCSP	NAME	FUNCTION	
1	B1	Vcc	Positive-Supply Voltage Input	
2	A1	NO1	Analog Switch 1—Normally Open Terminal	
3	A2	COM1	Analog Switch 1—Common Terminal	
4	A3	NC1	Analog Switch 1—Normally Closed Terminal	
5	A4	IN1	Digital Control Input for Analog Switch 1. A logic LOW on IN1 connects COM1 to NC1 and a logic HIGH connects COM1 to NO1.	
6	B4	GND	Ground	
7	C4	IN2	Digital Control Input for Analog Switch 2. A logic LOW on IN2 connects COM2 to NC2 and a logic HIGH connects COM2 to NO2.	
8	C3	NC2	Analog Switch 2—Normally Closed Terminal	
9	C2	COM2	Analog Switch 2—Common Terminal	
10	C1	NO2	Analog Switch 2—Normally Open Terminal	
EP (TDFN only)	—	EP	Exposed pad for TDFN package. Connect to GND.	

## Pin Description (MAX4763/MAX4765)

Р	IN			
12-Thin QFN	12-UCSP	NAME	FUNCTION	
1	A2	COM1	Analog Switch 1—Common Terminal	
2	A3	NC1	Analog Switch 1—Normally Closed Terminal	
3	A4	IN1	Digital Control Input for Analog Switch 1. A logic LOW on IN1 connects COM1 to NC1 and a logic HIGH connects COM1 to NO1.	
4	B3	CMP-	Comparator Inverting Input	
5	B4	GND	Ground	
6	C4	IN2	Digital Control Input for Analog Switch 2. A logic LOW on IN2 connects COM2 to NC2 and a logic HIGH connects COM2 to NO2.	
7	C3	NC2	Analog Switch 2—Normally Closed Terminal	
8	C2	COM2	Analog Switch 2—Common Terminal	
9	C1	NO2	Analog Switch 2—Normally Open Terminal	
10	B2	CMPO	Comparator Output	
11	B1	Vcc	Positive-Supply Voltage Input	
12	A1	NO1	Analog Switch 1—Normally Open Terminal	
EP	—	EP	Exposed pad. Connect to GND.	

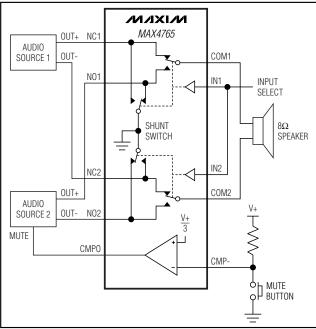


Figure 1. Typical Operating Circuit

### **Detailed Description**

The MAX4762–MAX4764/MAX4764A/MAX4765 are low on-resistance, low-voltage, dual SPDT analog switches that operate from a +1.8V to +5.5V supply and are fully specified for nominal 3.0V applications. The devices feature a negative signal capability that allows signals below ground to pass through without distortion and have break-before-make switching.

The MAX4763/MAX4765 feature a comparator that can be used for headphone or mute detection. The comparator threshold is internally generated to be approximately 1/3 of  $V_{CC}$ . The MAX4764/MAX4764A/MAX4765 feature an internal shunt switch to discharge any capacitance at the NO and NC connection points. This reduces the click-and-pop sounds that occur when switching audio signals.

## **Applications Information**

#### **Digital Control Inputs**

The MAX4762–MAX4764/MAX4764A/MAX4765 logic inputs accept up to +5.5V, regardless of supply voltage. For example, with a +3.3V supply, IN\_ can be driven low to GND and high to +5.5V allowing for mixing of logic levels in a system. Driving IN\_ rail-to-rail minimizes power consumption. For a +1.8V supply voltage, the logic thresholds are 0.5V (low) and 1.4V (high); for a +5V supply voltage, the logic thresholds are 0.8V (low) and 2.0V (high).

#### Analog Signal Levels

The on-resistance of the MAX4762–MAX4764/ MAX4764A/MAX4765 changes very little for analog input signals across the entire supply voltage range (see the *Typical Operating Characteristics*). The switches are bidirectional, so the NO\_, NC\_, and COM\_ pins can be either inputs or outputs.

The MAX4762–MAX4764/MAX4764A/MAX4765 pass signals as low as V<sub>CC</sub> - 5.5V, including signals below ground with minimal distortion.

#### Comparator (MAX4763/MAX4765)

The MAX4763/MAX4765 include a comparator that can be used for mute and headphone detection functions. The positive terminal of the comparator is internally set to V<sub>CC</sub> / 3. When the negative terminal (CMP-) is below the threshold, the comparator output (CMPO) is a logic high. When CMP- rises above V<sub>CC</sub> / 3, CMPO is a logic low.

The comparator threshold of V<sub>CC</sub> / 3 allows for detection of headphones because headphone audio signals are typically biased to V<sub>CC</sub> / 2.

#### Shunt Switch (MAX4764/MAX4764A/MAX4765)

The 100 $\Omega$  shunt switches on the MAX4764/MAX4764A/MAX4765 automatically discharge any capacitance at the NC\_ or NO\_ terminals when they are unconnected to COM\_. This reduces audible click-and-pop sounds that occur when switching between audio sources.

Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.

#### Power-Supply Sequencing and Overvoltage Protection

Caution: Do not exceed the absolute maximum ratings since stresses beyond the listed ratings may cause permanent damage to the device.

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V<sub>CC</sub> before applying analog signals, especially if the analog signal is not current-limited.

## **UCSP** Applications Information

For the latest application details on UCSP construction, dimensions, tape carrier information, printed circuit board techniques, bump-pad layout, and recommended reflow temperature profile, as well as the latest information on reliability testing results, go to the Maxim's website at www.maxim-ic.com/ucsp and search for the Application Note, "UCSP—A Wafer-Level Chip-Scale Package."



## **Test Circuits/Timing Diagrams**

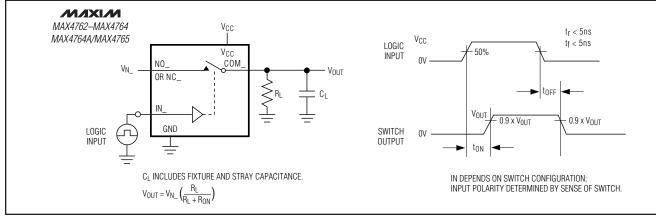


Figure 2. Switching Time

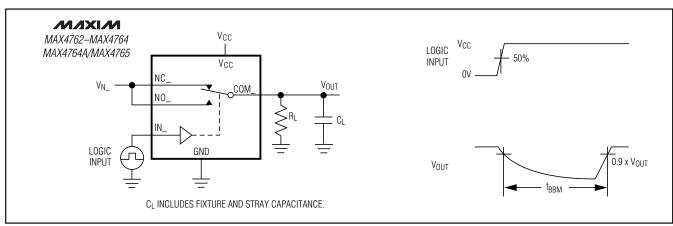


Figure 3. Break-Before-Make Interval

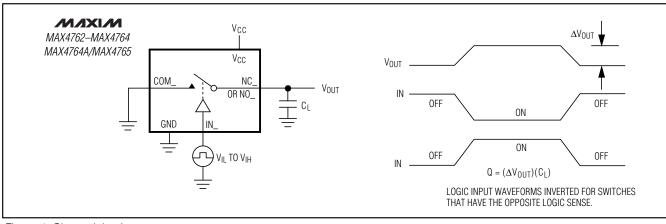


Figure 4. Charge Injection

9



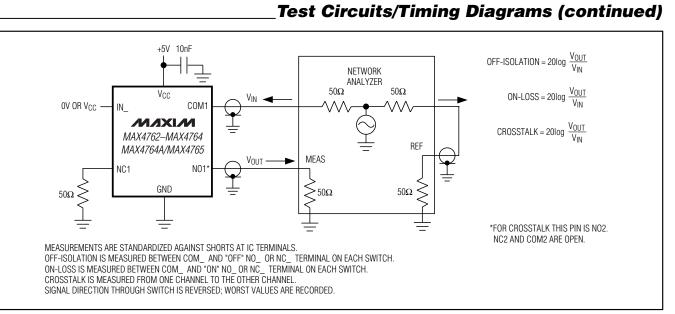


Figure 5. On-Loss, Off-Isolation, and Crosstalk

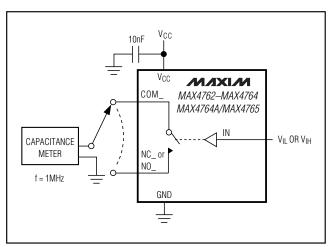
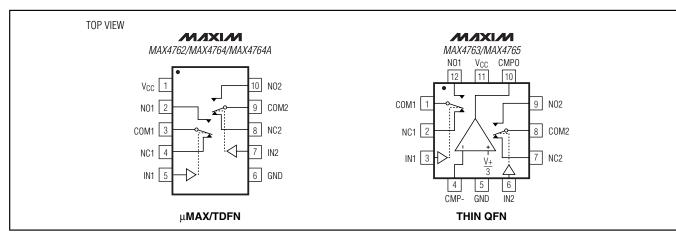


Figure 6. Channel Off/On-Capacitance

## **Pin Configurations/Functional Diagrams/Truth Table (continued)**



## \_Ordering Information (continued)

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4763EBC-T	-40°C to +85°C	12 UCSP-12	ABS
MAX4763ETC	-40°C to +85°C	12 Thin QFN	AAED
MAX4764ETB	-40°C to +85°C	10 TDFN	ACH
MAX4764EUB	-40°C to +85°C	10 µMAX	_
MAX4764EBC-T	-40°C to +85°C	12 UCSP-12	ABV
MAX4764AETB	-40°C to +85°C	10 TDFN	AQP
MAX4765EBC-T	-40°C to +85°C	12 UCSP-12	ABT
MAX4765ETC	-40°C to +85°C	12 Thin QFN	AAEE

## \_Chip Information

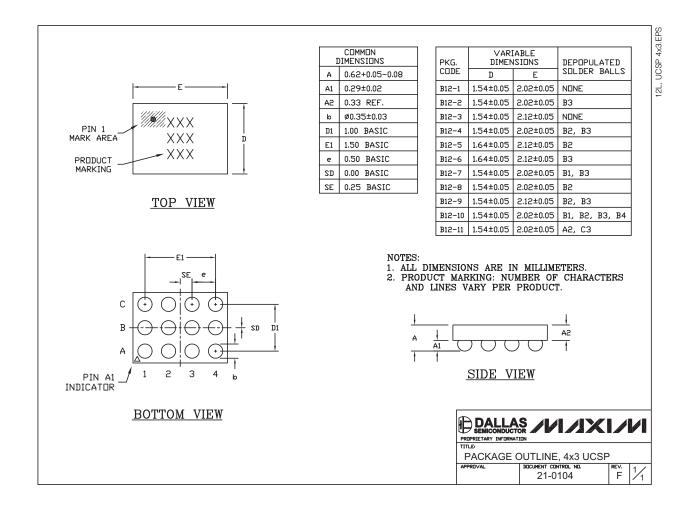
TRANSISTOR COUNT: 769 PROCESS: BICMOS

## **Selector Guide**

PART	COMPARATOR	SHUNT	PACKAGE SIZE (mm)
MAX4762EBC-T	No	No	1.5 x 2.0
MAX4762ETB	No	No	3.0 x 3.0
MAX4762EUB	No	No	3.0 x 5.0
MAX4763EBC-T	Yes	No	1.5 x 2.0
MAX4763ETC	Yes	No	4.0 x 4.0
MAX4764EBC-T	No	Yes	1.5 x 2.0
MAX4764ETB	No	Yes	3.0 x 3.0
MAX4764AETB	No	Yes	3.0 x 3.0
MAX4764EUB	No	Yes	3.0 x 5.0
MAX4765EBC-T	Yes	Yes	1.5 x 2.0
MAX4765ETC	Yes	Yes	4.0 x 4.0

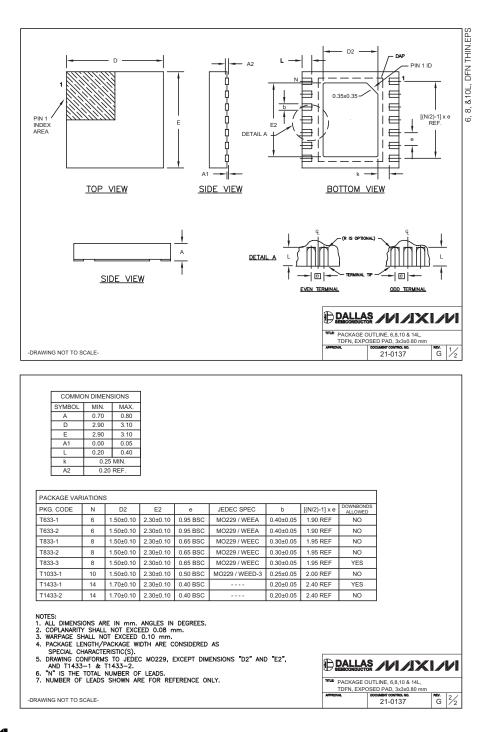
### Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



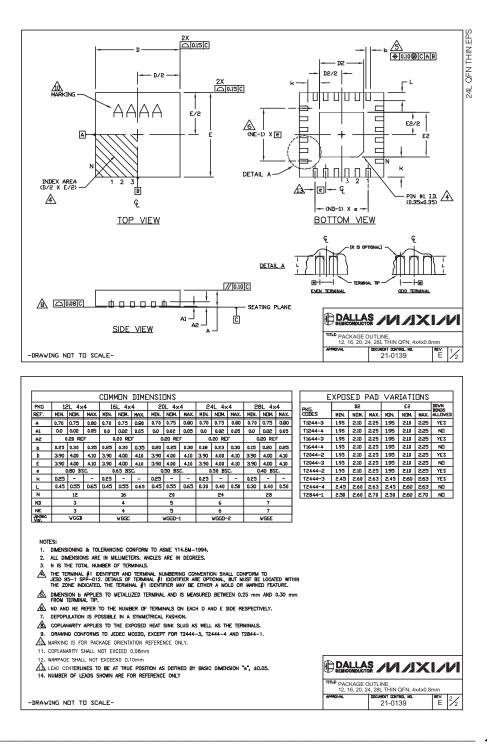
### Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



### \_Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)



M/IXI/M